

Photo DMOS-FET Relay

Description

The **LU834** is a 1-Form B solid state relay in an 6 pin DIP package that employs optically coupled MOSFET technology to provide 3750V/5000V of input to output isolation. The optically coupled input is controlled by a highly efficient GaAlAs infrared LED and MOS FETs on the output side.

Features

- Low driver power requirements (TTL/CMOS Compatible)
- Contact form: Normally-On (1b)
- Load voltage: 60V max.
- On-Resistance: 3Ω max.
- 3750 / 5000 Vrms Input/Output isolation
- Tape & Reel version available

Applications

- Telecommunications (PC, Electronic notepad)
- Measuring and Testing equipment
- Industrial control
- Security equipments
- High speed inspection machine

Outline Dimensions

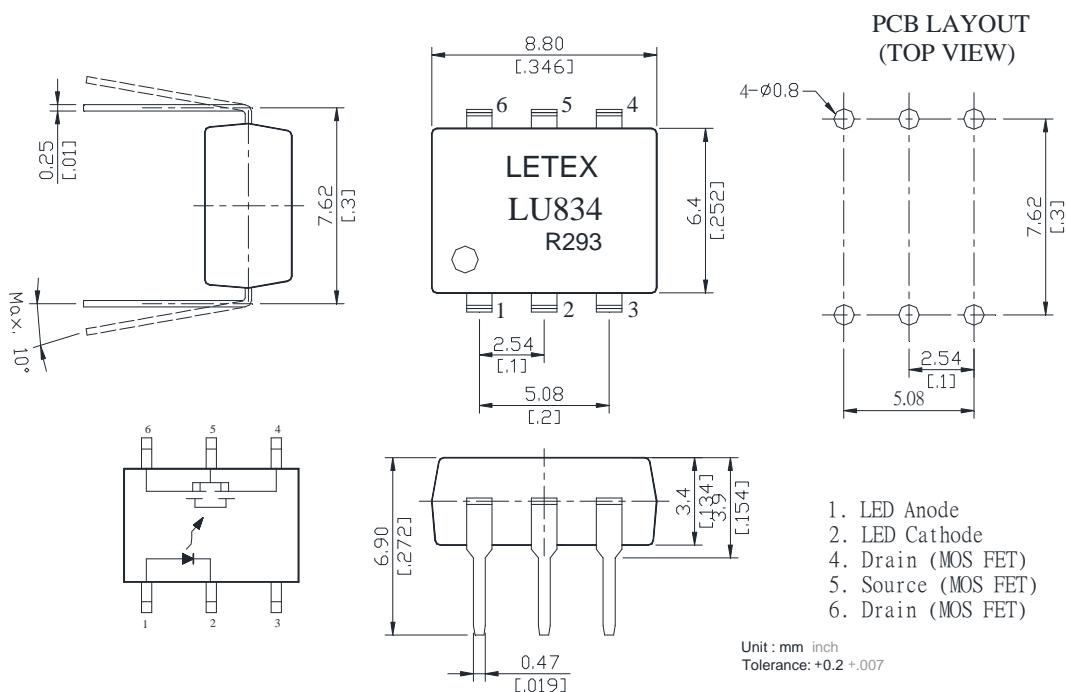


Photo DMOS-FET Relay Specifications

Part Name: LU834

(Load voltage: 60V / Load current: 500mA)

Absolute Maximum Ratings (Ambient Temperature: 25°C)

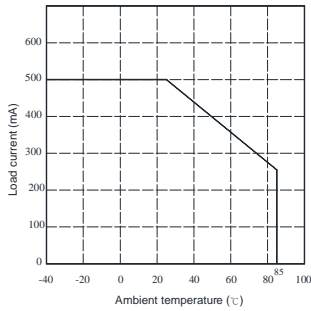
Item	Symbol	Value	Units	Note	
Input	Continuous LED Current	IF	50	mA	
	Peak LED Current	IFP	500	mA	f=100Hz, duty=1%
	LED Reverse Voltage	VR	5	V	
	Input Power Dissipation	PIn	75	mW	
Output	Load Voltage	VL	60	V(AC peak or DC)	
	Load Current	IL	500	mA	
	Peak Load Current	IPeak	0.6	A	1ms(1 pulse)
	Output Power Dissipation	Pout	300	mW	
Total Power Dissipation	PT	350	mW		
I/O Breakdown Voltage	VIO	3750	Vrms	RH=60%, 1min	
I/O Breakdown Voltage(Suffix-V)	VIO	5000	Vrms	RH=60%, 1min	
Operating Temperature	Topr	-40 to +85	°C		
Storage Temperature	Tstg	-40 to +100	°C		
Pin Soldering Temperature	Tsol	260	°C	10 sec max.	

Electrical Specifications (Ambient Temperature: 25°C)

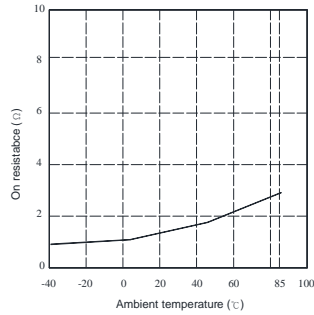
Item	Symbol	MIN.	TYP.	MAX.	Units	Conditions
Input	LED Forward Voltage	VF	1.2	1.5	V	IF=10mA
	Operation LED Current	IFon	0.5	5.0	mA	
	Recovery LED Current	IFoff	0.1	0.4	mA	
	Recovery LED Voltage	VFoff	0.5		V	
Output	On-Resistance	Ron	1	3	Ω	IF=0mA,IL=100mA, Time to flow is within 1 sec.
	Off-State Leakage Current	ILeak		1	uA	IF=10mA,VL=60V
	Output Capacitance	Cout	165		pF	IF=10mA,VL=0V, f=1MHz
Transmis sion	Turn-Off Time	Toff	0.5	3.0	ms	IF=10mA,
	Turn-On Time	Ton	0.25	1.0	ms	IL=100mA
Coupled	I/O Isolation Resistance	RIO	10 ¹⁰		Ω	DC500V
	I/O Capacitance	CIO	0.8		pF	f=1MHz

Reference Data

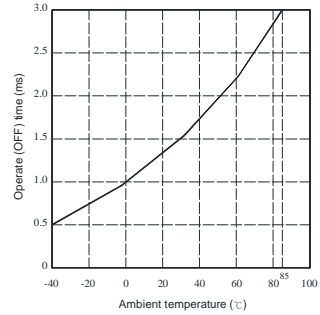
Load current Vs. Ambient temperature



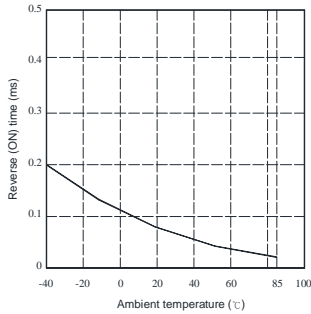
On resistance Vs. Ambient temperature



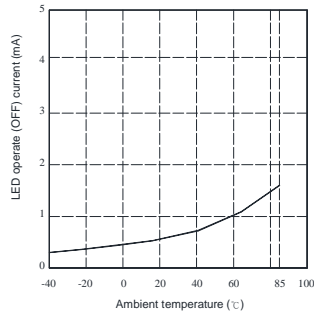
Operate (OFF) time Vs. Ambient temperature



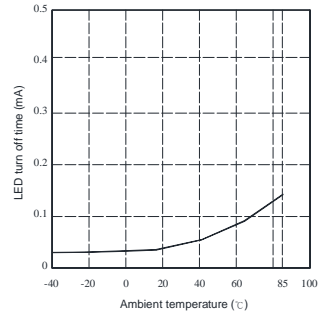
Reverse (ON) time Vs. Ambient temperature



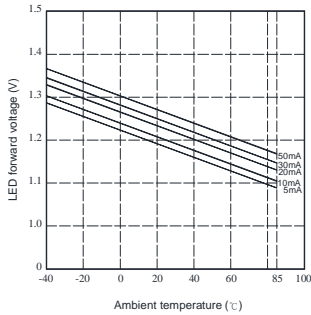
LED operate (OFF) current Vs. Ambient temperature



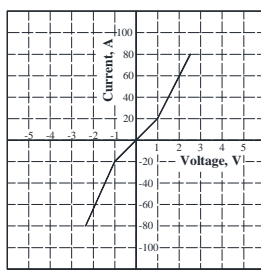
LED turn off current Vs. Ambient temperature



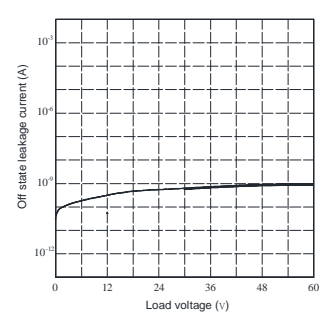
LED forward voltage Vs. Ambient temperature



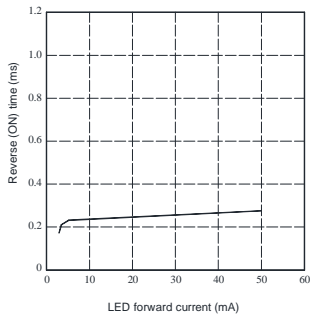
Voltage Vs. current characteristics of output at MOS portion



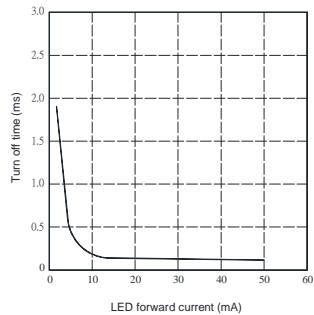
Off state leakage current Vs. Load voltage characteristics



LED forward current Vs. Reverse (ON) time characteristics



LED forward current Vs. Operate (OFF) time characteristics



Applied voltage Vs. output capacitance characteristics

